

Background Free NanoPhotoconductivity Correlated With Topography of Photovoltaics & 2D Material Devices

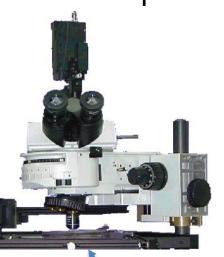
http://www.nanonics.co.il/ap plicationscontent/photovoltaic s-photoconductivity

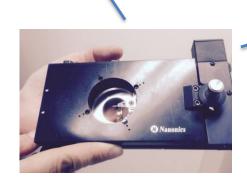


The System

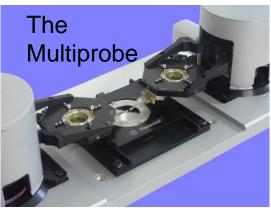
A Variety of Different Possibilities From Simple to Sophisticated

Single Probe Systems
With Nanonics
Microscope
Solutions or Your
Own Microscope







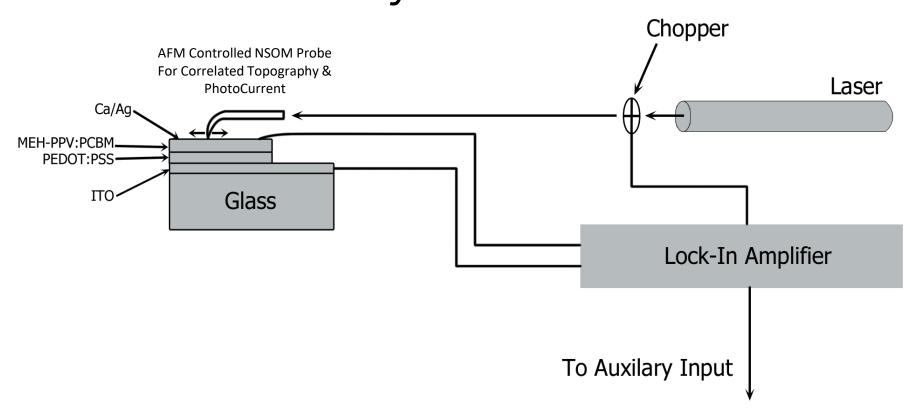


Multiprobe Systems



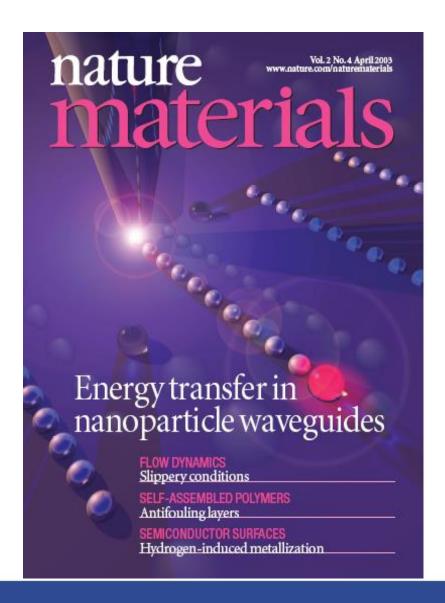


NANONICS An Exemplary Photoconductivity Measurement Layout As Provided by Nanonics





Over Two Decades Nanonics Has Provided Point Nanolllumination Sources With No Background For Optical NanoCharacterization Corelated With Topography



Over 1800 Citations



A NanoToolKitTM of Exclusive Functional Probes

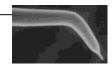


NanoOptical Light Source

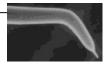


Plasmonic NanoProbes with Single Gold NanoParticles But Other Nanoparticles Also Possible Such As Co Possible





Glass Insulated Coaxial NanoElectrical



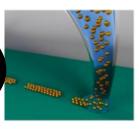


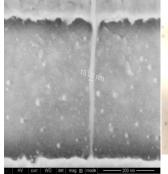
Nanopipettes for: Ionic Conductance, NanoFountain Pens for Liquid & Gas Delivery & Deposition,

NanoEvacuation



All probes patented & nano-fabricated **By Nanonics**



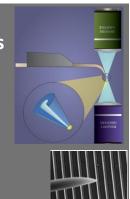


Optically Friendly Unobstructed Optical Axis

• Non-Obscuring Non-**Interfering Cantilevers**

 Probe Tips Exposed To The Optical Axis

•All Probes Allow On-line Raman



Nanonics Probes are MultiProbe Friendly



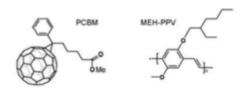


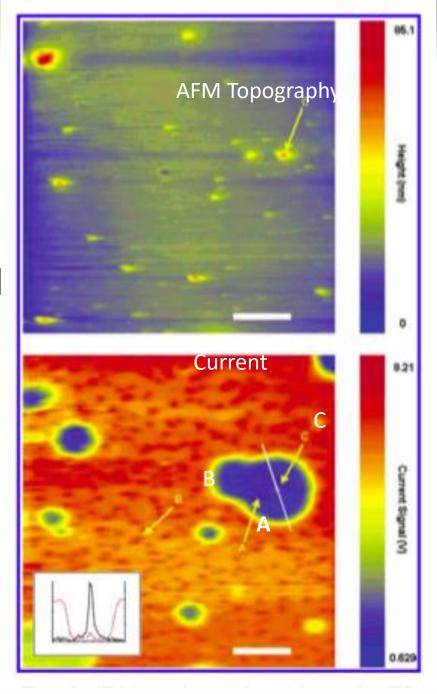
Exclusively Available For Nanonics Customers Only

The New Horizon in Photoconductivty



Correlated
AFM Topography
&
Current Images
of an ITO/ PEDO1
PSS/MEH-PPVPBCM/Ca/Ag
Solar Cell Device





The feature marked C corresponds to a small bright feature in the center of the large dark region (A) of the current image is also observed in the AFM image

The inset in the bottom image shows the height (black, solid) and current (red, dotted) traces taken along the white line. The scale bar is 5 μ m in length.

NANO LETTERS 2004 Vol. 4, No. 2 219-223



Near-field scanning photocurrent microscopy (NSPM) measurements

Photovoltaic devices based on p-xylene processed poly(9,9'dioctylfluorene-co-bis-N,N'-(4,butylphenyl)bis-N,N'-phenyl-1,4phenylene-diamine) [PFB] and poly(9,9'dioctylfluorene-cobenzo-thiadiazole) [F8BT] blend films

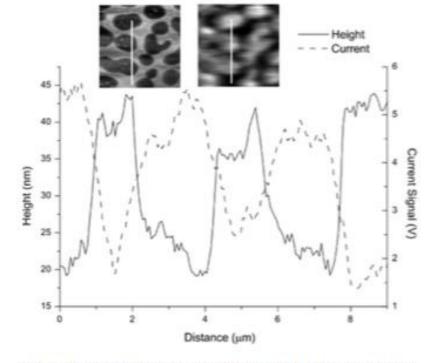


Figure 4. Cross-sectional traces of the AFM image and current map of Figure 3.

Current generation occurs primarily from within the micron-sized phase-segregated domains, with the PFB-rich phase contributing significantly more current than the surrounding F8BT-rich regions.

NANO

2507

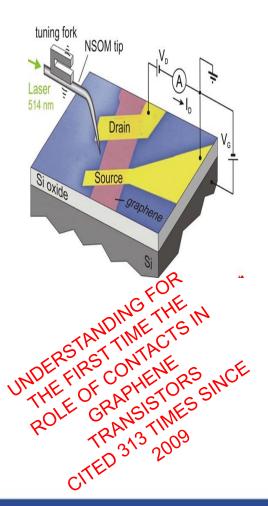
LETTERS

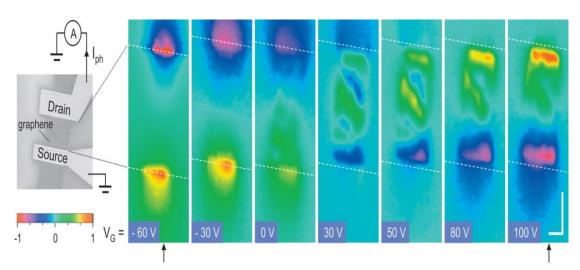
2004 Vol. 4,

No. 12 2503-



IBM Produced Photocurrent Images of A Graphene Transistor As A Function Of Voltage With Without Background Using Nanometric Confinement of Illumination in X Y and Z With NSOM





PHYSICAL REVIEW B 79, 245430 (2009)

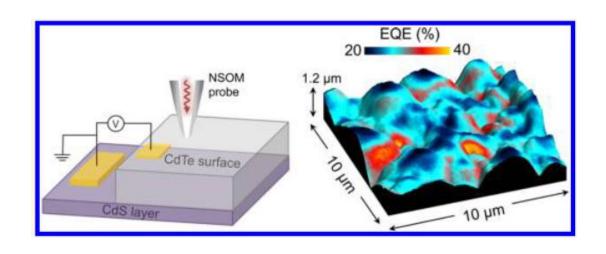


Super-resolution Near-Field Photocurrent Measurements

The Full System Includes:

>NanoPhotoconductivity
System Correlated With
One or Two Probes With
Full Controller and Imaging
Processing Software
>Laser As Chosen For The
Specific Application with
Fiber Coupler
>Appropriate Femtoamp

Current Amplifier
>Stand or Interface To Any
Upright or Inverted
Microscope



Paper: Leite, M. S. *et al.* Nanoscale Imaging of Photocurrent and Efficiency in CdTe Solar Cells. *ACS Nano* **8**, 11883–11890 (2014).



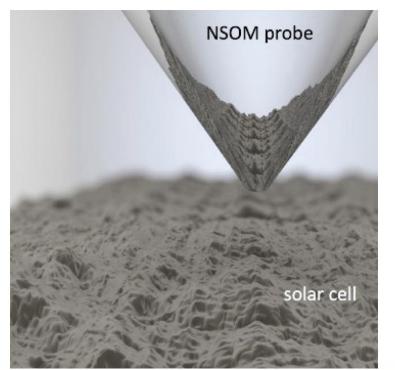
Nanolllumination

Near-field Illumination Without Background

Near-field Illumination

With

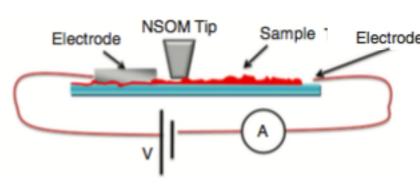
> Photocurrent Detection



Solar Cells



Single Probe And Multiprobe Configurations For Photoconductivity



Electrode All Single Probe Systems Allow for Such Electrical Connections

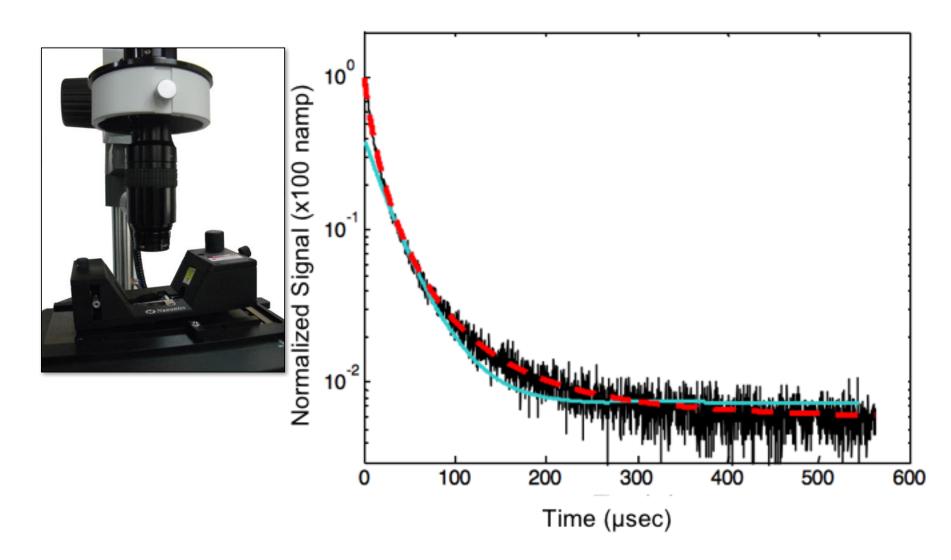


NSOM Tip Electrode Sample Electrode

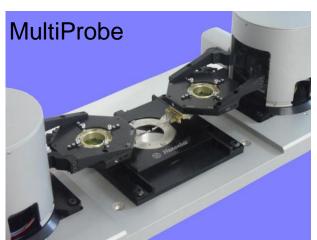
Multiprobe Systems Allow for **Electrical Connections at will**

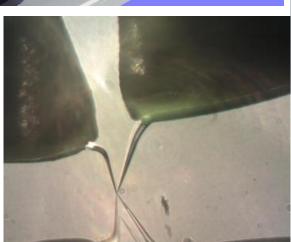


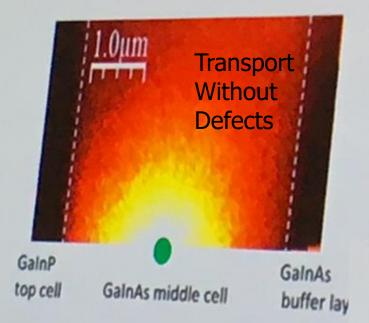
Allowing Time Resolved PhotoCurrent Measurement



Multiprobe Experiments With Two Nanometrically Confined Excitation Sources Also Allow Charge Transport In Solar Cells









What Investigators From IBM

Say In Their Published Work

- > NSOM overcomes the far-field resolution limit by bringing a light source of subwavelength size into close proximity to the sample surface
- The resolution of the image is limited by the size of the probe aperture and not by the wavelength of the light
- ➤ By analyzing the spatial variation in the PC in the vicinity of the metal contacts, we show that charge-transfer doping occurs underneath the contact metals and adjacent regions in the graphene channel, giving rise to asymmetric conduction characteristics for electrons and holes
- ➤ In a complementary experiment, we also demonstrate charge transfer and photocurrent generation at single-layer graphene SLG and multilayer graphene MLG interfaces
- A topographic image is acquired simultaneously with the PC image, allowing correlation of structural and PC properties at the same positions on the graphene transistor



A NanoToolKitTM of Exclusive Functional Probes



NanoOptical Light Source

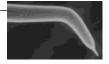


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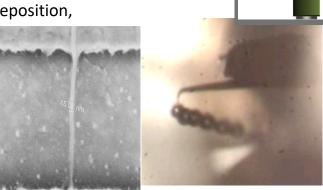
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NanoEvacuation



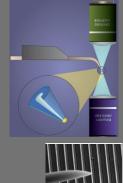
All probes patented & nano-fabricated **By Nanonics**





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- Probe Tips Exposed To The Optical Axis
- •All Probes Allow On-line Raman



Nanonics Probes are MultiProbe Friendly





Exclusively Available For Nanonics Customers Only



NANONICS Therefore Nanonics Is Proven In The Literature To Image With Excellent XY Morphological Fidelity Even Compared To FESEM



Contents lists available at ScienceDirect

Materials Letters

journal homepage: www.elsevier.com/locate/matlet



Atomic force microscopy (AFM) and 3D confocal microscopy as alternative techniques for the morphological characterization of anodic TiO₂ nanoporous layers



Diego P. Oyarzún a,*, Omar E. Linarez Pérez b, Manuel López Teijelo b, César Zúñiga a, Eduardo Jeraldo a, Daniela A. Geraldo a,c, Ramiro Arratia-Perez a,c

The Tuning Fork Uniquely Provides A High Quality Factor, Q, For Ultra Sensitivity In AFM And In AFM Morphology. This Is Not Available With Any Beam Bounce Feedback AFM (see green highlighted customer description). Also True Non-contact Is Achieved With The Nanonics Tuning Fork Systems. Thus, Nanonics Provides The Only AFM Systems That Allow For Switching Between AFM And STM Feedback With The Same Probe. Proving Noncontact AFM Operation

4. Conclusions

The characterization of the surface morphology by FESEM and TEM was compared with the results obtained by both AFM and 3D confocal microscopy. Characterization of porous oxide layers by AFM shows that the microscope with tuning fork configuration (intermittent mode) presents advantages over the beam bounce configuration (contact mode) namely high sensitivity in amplitude and phase, as well as high mechanical quality factor. This, in turn, allows the acquisition of real images of high resolution of the organized nanostructures. Additionally, the average radius values obtained from the AFM experiments are very similar to those obtained from FESEM images, which reflects that the morphological information obtained by atomic force microscopy for TiO2 nanotubes is reliable and representative of the properties of the system. In brief, the intermittent AFM mode using tuning fork configuration is a powerful tool for characterizing highly ordered porous nanostructures as it provides conclusive information about the morphology of this one-dimensional nanostructures. On the

The New Horizon in Photoconductivty

^a Centro de Nanociencias Aplicadas (CENAP), Facultad de Ciencias Exactas, Universidad Andrés Bello, Chile, Avenida República 275, Santiag b Instituto de Investigaciones en Fisicoquímica de Córdoba (INFIQC), Facultad de Ciencias Químicas, Universidad Nacional de Córdoba, Hayı Medina Allende, 5000 Córdoba, Argentina

c Núcleo Milenio de Ingeniería Molecular para Catálisis y Biosensores, ICM, Chile



Readily Integrated With Available Or Future Acquisition of Raman MicroSpectroscopy Systems



The MV1500

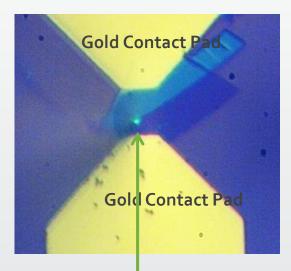




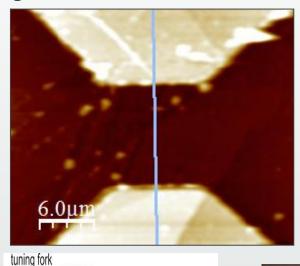


Near-field Scanning Optical Photoconductivity Correlated With Raman

Optical Image of Graphene With Different Doping Content Areas Showing Altered Optical Contrast Due To Index of Refraction Change



Reflection Optical image above clearly shows the green spot of a 532nm laser on the sample without the probe shaft obscuring any of the light. A diagrammatic representation is seen to the right.



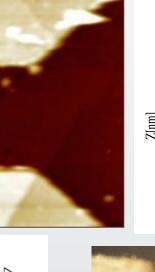
NSOM tip

Drain

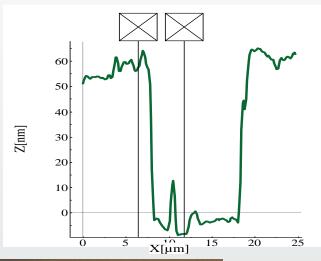
Source

514 nm

Si oxide







Raman Correlation Following Slide

The New Horizon in Photoconductivity

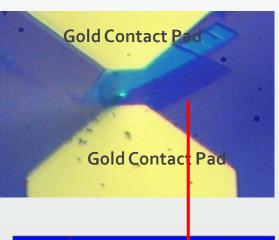
NSOM

Probe



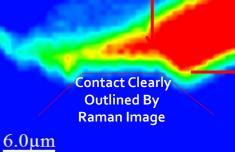
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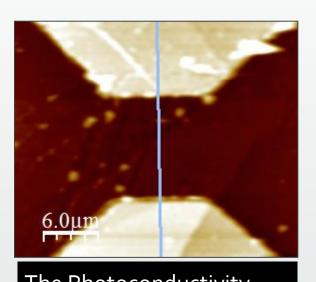


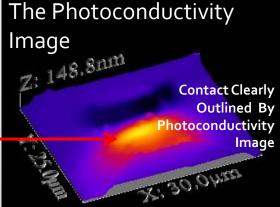
AFM Raman Image

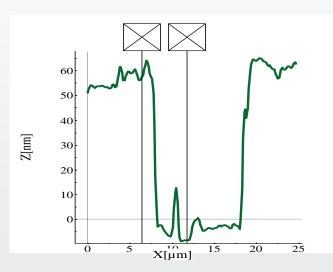
At 256 cm⁻¹

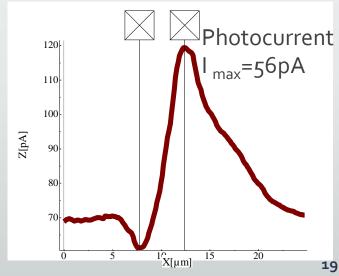


Raman clearly characterizes the chemical nature of material that results in the photoconductivity









Unlimited Possibilities